

MC79XX/MC79XXA/LM79XX

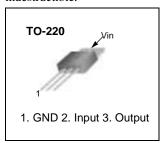
3-Terminal 1A Negative Voltage Regulator

Features

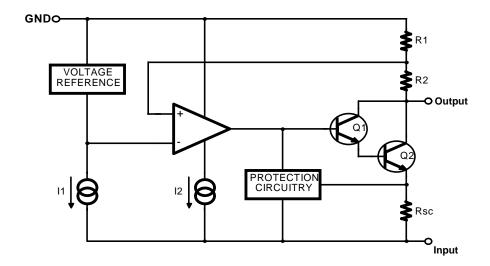
- Output Current in Excess of 1A
- Output Voltages of -5, -6, -8, -9, -10, -12, -15, -18 and -24V
- · Internal Thermal Overload Protection
- · Short Circuit Protection
- Output Transistor Safe Operating Area Compensation

Description

The MC79XX / MC79XXA/ LM79XX series of three terminal negative regulators are available in TO-220 package and with several fixed output voltages, making them useful in a wide range of applications. Each type employs internal current limiting, thermal shut down and safe operating area protection, making it essentially indestructible.



Internal Block Digram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage	VI	-35	V
Thermal Resistance Junction-Case (Note1)	R _θ JC	5	°C/W
Thermal Resistance Junction-Air (Note1, 2)	$R_{ heta JA}$	65	C/ VV
Operating Temperature Range	TOPR	0 ~ +125	°C
Storage Temperature Range	Tstg	-65 ~ +150	°C

Note:

- Thermal resistance test board Size: 76.2mm * 114.3mm * 1.6mm(1S0P) JEDEC standard: JESD51-3, JESD51-7
- 2. Assume no ambient airflow

Electrical Characteristics (MC7905/LM7905)

(VI = -10V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Cone	ditions	Min.	Тур.	Max.	Unit
		TJ = +25°C		-4.8	-5.0	-5.2	
Output Voltage	Vo	I _O = 5mA to 1A, V _I = -7V to -20V	-	-4.75	-5.0	-5.25	V
Line Regulation (Note3)	ΔVΩ	T _J = +25°C	V _I = -7V to -25V	-	35	100	mV
Line Regulation (Notes)	ΔνΟ	1J = +25 C	V _I = -8V to -12V	-	8	50	IIIV
Load Regulation (Note2)	ΔVΩ	T _J = +25°C I _O = 5mA to 1.5	IO = 5mA to 1.5A		10	100	m\/
Load Regulation (Note3)	ΔνΟ	T _J =+25°C I _O = 250mA to 7			3	50	mV
Quiescent Current	IQ	T _J =+25°C	T _J =+25°C			6	mA
Quiocoont Current Change	AIO.	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔlQ	$V_{I} = -8V \text{ to } -25V$,	-	0.1	0.8	ША
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	- 0.4	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k TA =+25°C	кНz	-	40	-	μV
Ripple Rejection	RR	f = 120Hz ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	TJ =+25°C, VI =	-35V	-	300	-	mA
Peak Current	IPK	TJ =+25°C		-	2.2	-	Α

^{3.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7906) (Continued)

(VI = -11V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Cone	ditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		-5.75	-6	-6.25	
Output Voltage	Vo	IO = 5mA to 1A, $V_I = -9V \text{ to } -21V$	Po ≤ 15W	-5.7	-6	-6.3	V
Line Regulation (Note1)	ΔVΩ	T _J = +25°C	$V_{I} = -8V \text{ to } -25V$	-	10	120	mV
Line Regulation (Note I)	ΔνΟ	1J = +25 C	V _I = -9V to -13V	-	5	60	IIIV
Load Regulation (Note1)	ΔVο	T _J = +25°C I _O = 5mA to 1.5A		-	10	120	mV
Load Negulation (Note 1)	ΔνΟ	TJ =+25°C IO = 250mA to 7			3	60	IIIV
Quiescent Current	IQ	TJ =+25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔiQ	V _I = -8V to -25V		-	0.1	1.3	IIIA
Temperature Coefficient of V _D	ΔVo/ΔΤ	IO = 5mA		-	-0.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T _A =+25°C	Hz	-	130	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	-35V	-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7908) (Continued)

(VI = -14V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		-7.7	-8	-8.3	
Output Voltage	Vo	IO = 5mA to 1A V _I = -10V to -2	-	-7.6	-8	-8.4	V
Line Regulation (Note1)	ΔVΩ	T _J = +25°C	V _I = -10.5V to -25V	-	10	160	mV
Line Regulation (Note1)	ΔνΟ	1J = +25 C	V _I = -11V to -17V	-	5	80	IIIV
Load Regulation (Note1)	ΔVΩ	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5$	T _J = +25°C I _O = 5mA to 1.5A T _J =+25°C I _O = 250mA to 750mA		12	160	mV
Load Negulation (Note I)	ΔνΟ				4	80	IIIV
Quiescent Current	IQ	TJ =+25°C		-	3	6	mA
Quiescent Current Change	Alo	ΔI_Q $I_O = 5mA \text{ to } 1A$		-	0.05	0.5	mA
Quiescent Current Change	ΔIQ	V _I = -10.5V to	-25V	-	0.1	1	ША
Temperature Coefficient of VD	ΔVo/ΔΤ	IO = 5mA		-	-0.6	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100 T _A =+25°C	OkHz	-	175	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V		54	60	1	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	٧
Short Circuit Current	Isc	TJ = +25°C, VI	= -35V	-	300	-	mA
Peak Current	IPK	T _J = +25°C		i	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7909) (Continued)

(VI = -15V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Con	ditions	Min.	Тур.	Max.	Unit
		T _J = +25°C	T _J = +25°C		-9.0	-9.3	
Output Voltage	Vo	IO = 5mA to 1A, V _I = -1.5V to -23		-8.6	-9.0	-9.4	V
Line Regulation (Note1)	ΔVΩ	T _J = +25°C	VI = -11.5V to -26V	-	10	180	mV
Line Regulation (Note I)	ΔνΟ	1J = +25 C	V _I = -12V to -18V	-	5	90	IIIV
Load Regulation (Note1)	ΔVο	$I_{\Omega} = 5 \text{mA to } 1.5 \text{A}$		-	12	180	mV
Load (Note I)	ΔνΟ	T _J = +25°C I _O = 250mA to 7			4	90	''''
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔiQ	V _I = -11.5V to -2	e6V	-	0.1	1	IIIA
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.6	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T _A = +25°C	:Hz	-	175	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	TJ = +25°C, VI = -35V		300	-	mA
Peak Current	IPK	T _J = +25°C		-	2.2	-	А

^{1.} Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7910) (Continued)

(VI = -17V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Con	ditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		-9.6	-10	-10.4	
Output Voltage	Vo	IO = 5mA to 1A, VI = -12V to -28	Pd ≤ 15W	-9.5	-10	-10.5	V
Line Regulation (Note1)	ΔVο	T _J = +25°C	V _I = -12.5V to -28V	-	12	200	mV
Line Regulation (Note I)	ΔνΟ	1J = +25 C	V _I = -14V to -20V	-	6	100	1 1111
Load Regulation (Note1)	ΔVο	T _J = +25°C I _O = 5mA to 1.5A		-	12	200	mV
Load (Note I)	ΔνΟ	$T_J = +25^{\circ}C$ $I_O = 250 \text{mA to } 7$			4	100	1110
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔiQ	V _I = -12.5V to -2	8V	-	0.1	1	
Temperature Coefficient of VO	ΔVο/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	10Hz ≤ f ≤ 100kH T _A =+25°C	l z	-	280	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V		54	60	-	dB
Dropout Voltage	VD	TJ = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	T _J = +25°C, V _I = -35V		-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7912) (Continued)

(VI = -19V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		-11.5	-12	-12.5	
Output Voltage	Vo	IO = 5mA to 1A, $V_I = -15.5V \text{ to } -2$		-11.4	-12	-12.6	s V
Line Regulation (Note1)	ΔVΩ	T _J = +25°C	V _I = -14.5V to -30V	-	12	240	mV
Line Regulation (Note1)	ΔνΟ	V _I = -16V to -22V		-	6	120	IIIV
Load Regulation (Note1)	ΔVΩ	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5A$	IO = 5mA to 1.5A		12	240	mV
Load Regulation (Note 1)	ΔνΟ	$T_J = +25^{\circ}C$ $I_O = 250mA \text{ to } 7$			- 4	120	IIIV
Quiescent Current	IQ	TJ = +25°C	T _J = +25°C		3	6	mA
Quiescent Current Change	Alo	ΔIQ IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔIQ	$V_I = -14.5V \text{ to } -3$	80V	-	0.1	1	ША
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T _A = +25°C	Hz	-	200	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V			60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	-35V	-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7915) (Continued)

(VI = -23V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Con	ditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		-14.4	-15	-15.6	
Output Voltage	Vo	IO = 5mA to 1A, $V_I = -18V \text{ to } -30$		-14.25	-15	-15.75	V
Line Regulation (Note1)	ΔVΩ	T _J = +25°C	VI = -17.5V to -30V	-	12	300	mV
Line Regulation (Note 1)	ΔνΟ	1J = 1 25 C	V _I = -20V to -26V	-	6	150	IIIV
Load Regulation (Note1)	ΔVο	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5a$	A	-	12	300	mV
Load Negulation (Note 1)	Δ۷Ο	$T_J = +25^{\circ}C$ $I_O = 250 \text{mA to } 7$			4	150	IIIV
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	$I_O = 5mA \text{ to } 1A$		-	0.05	0.5	mA
Quiescent Current Change	ΔiQ	$V_I = -17.5V \text{ to } -3$	30V	-	0.1	1	
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.9	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T _A =+25°C	kHz	-	250	-	μV
Ripple Rejection	RR	f = 120Hz $\Delta V_I = 10V$		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	= -35V	-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7918) (Continued)

(VI = -27V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Con	ditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		-17.3	-18	-18.7	
Output Voltage	Vo	IO = 5mA to 1A, VI = -22.5V to -3		-17.1	-18	-18.9	V
Line Regulation (Note1)	ΔVΩ	T _J = +25°C	V _I = -21V to -33V	-	15	360	mV
Line Regulation (Note I)	ΔνΟ	11 = +23 C	V _I = -24V to -30V	-	8	180	IIIV
Load Regulation (Note1)	ΔVΩ	T _J = +25°C I _O = 5mA to 1.5A		-	15	360	mV
Load Negulation (Note 1)	ΔνΟ	T _J = +25°C l _O = 250mA to 7			5	180	
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiocaant Current Change	Alo	I _O = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔlQ	VI = -21V to -33V	V	-	0.1	1	IIIA
Temperature Coefficient of VD	ΔVo/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T _A = +25°C	Hz	-	300	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	T _J = +25°C, V _I = -35V		-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7924) (Continued)

(VI = -33V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		-23	-24	-25	
Output Voltage	Vo	IO = 5mA to 1A, $V_I = -27V \text{ to } -38^{\circ}$		-22.8	-24	-25.2	V
Line Regulation (Note1)	ΔVο	T _J = +25°C	V _I = -27V to -38V	-	15	480	mV
Line Regulation (Note I)	ΔνΟ	1J = 1 23 C	$V_I = -30V \text{ to } -36V$	-	8	180	
Load Regulation (Note1)	ΔVο	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5n$	Ą	-	15	480	mV
Load (Negulation (Note 1)	ΔνΟ	$T_J = +25^{\circ}C$ $I_O = 250 \text{mA to } 7$	50mA	-	5	240	
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	$I_O = 5mA$ to $1A$		-	0.05	0.5	mA
Quiescent Current Change	ΔiQ	VI = -27V to -38	V	=	0.1	1	1 111/4
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T _A = +25°C	кНz	-	400	-	μV
Ripple Rejection	RR	f = 120Hz ΔVI = 10V			60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	35V	-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7905A) (Continued)

(VI = -10V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Ce	onditions	Min.	Тур.	Max.	Unit
		$T_J = +25^{\circ}C$		-4.9	-5.0	-5.1	
Output Voltage	Vo	V _I = -7V to -20V		- 4.8	-5.0	-5.2	V
		T _J = +25°C	V _I = -7V to -20V I _O =1A	-	5	50	
Line Regulation (Note1)	ΔVο	1J = +25 C	V _I = -8V to -12V I _O =1A	-	2	25	mV
Line Regulation (Note I)	ΔνΟ	V _I = -7.5V to -25V	V	-	7	50	IIIV
		V _I = -8V to -12V , I _O =1A		-	7	50	
		TJ =+25°C, IO =	5mA to 1.5A	-	10	100	
Load Regulation (Note1)		$T_J = +25^{\circ}C$ IO = 250mA to 750mA		-	3	50	mV
Quiescent Current	ΙQ	T _J = +25°C			3	6	mA
Quiagont Current Change	Alo	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔlQ	V _I = -8V to -25V		-	0.1	0.8	MA
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	- 0.4	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kl T _A = +25°C	Hz	-	40	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	-35V	-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7912A) (Continued)

(VI = -19V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		-11.75	-12	-12.25	
Output Voltage	Vo	IO = 5mA to 1A, V _I = -15.5V to -2		-11.5	-12	-12.5	V
		T _J = +25°C	V _I = -14.5V to -27V lo = 1A	-	12	120	
Line Regulation (Note1)	ΔVο	1J = +23 C	V _I = -16V to -22V lo = 1A	-	6	60	mV
		$V_{I} = -14.8V \text{ to } -3$	0V	-	12	120	
		V _I = -16V to -22V, lo = 1A		-	12	120	
Load Demulation (Noted)	ΔVο	T _J = +25°C l _O = 5mA to 1.5/	Γ _J = +25°C _O = 5mA to 1.5A		12	150	mV
Load Regulation (Note1)		TJ = +25°C IO = 250mA to 750mA		-	4	75	IIIV
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Ouissant Current Change		$I_O = 5mA \text{ to } 1A$		-	0.05	0.5	A
Quiescent Current Change	ΔlQ	VI = -15V to -30	V	-	0.1	1	mA
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T _A = +25°C	Hz	-	200	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V			60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	T _J = +25°C, V _I =	: -35V	-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

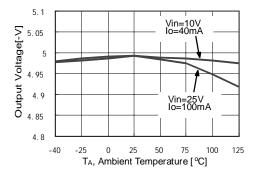
Electrical Characteristics (MC7915A) (Continued)

(VI = -23V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
	Vo	T _J = +25°C		-14.7	-15	-15.3	V
Output Voltage		IO = 5mA to 1A, PO ≤ 15W VI = -18V to -30V		-14.4	-15	-15.6	
Line Regulation (Note1)	ΔVο	TJ = +25°C	V _I = -17.5V to -30V Io = 1A	-	12	150	mV
			VI = -20V to -26V Io = 1A	-	6	75	
		V _I = -17.9V to -30V		-	12	150	
		V _I = -20V to -26V, Io = 1A		-	6	150	
Load Regulation (Note1)	ΔVο	$T_{J} = +25^{\circ}C$ $I_{O} = 5mA \text{ to } 1.5A$		-	12	150	mV
		T _J = +25°C I _O = 250mA to 750mA		-	4	75	
Quiescent Current	lQ	T _J = +25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	I _O = 5mA to 1A		-	0.05	0.5	mA
		V _I = -18.5V to -30V		-	0.1	1	
Temperature Coefficient of VD	ΔVo/ΔΤ	IO = 5mA		-	-0.9	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz T _A = +25°C		-	250	-	μV
Ripple Rejection	RR	f = 120Hz $\Delta V_I = 10V$		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	T _J = +25°C, V _I = -35V		-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Typical Perfomance Characteristics



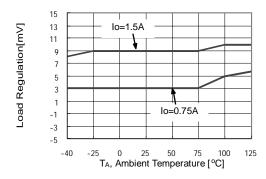
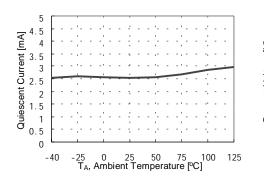


Figure 1. Output Voltage

Figure 2. Load Regulation



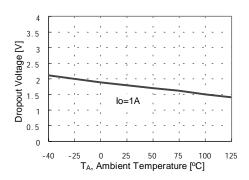


Figure 3. Quiescent Current

Figure 4. Dropout Voltage

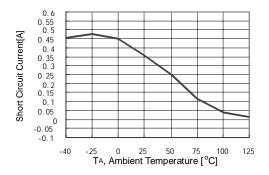


Figure 5. Short Circuit Current

Typical Applications

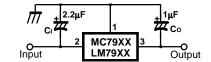


Figure 6. Negative Fixed output regulator

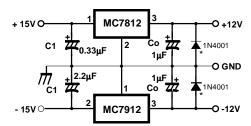


Figure 7. Split power supply (\pm 12V/1A)

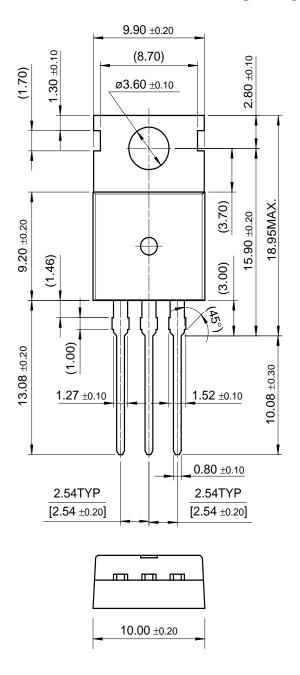
- (1) To specify an output voltage, substitute voltage value for "XX"
- (2) Required for stability. For value given, capacitor must be solid tantalum. If aluminium electronics are used, at least ten times value shown should be selected. C_I is required if regulator is located an appreciable distance from power supply filter.
- (3) To improve transient response. If large capacitors are used, a high current diode from input to output (1N400l or similar) should be introduced to protect the device from momentary input short circuit.

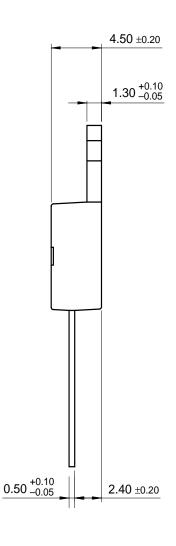
Mechanical Dimensions

Package

Dimensions in millimeters

TO-220





Ordering Information

Product Number	Output Voltage Tolerance	Package	Operating Temperature	
LM7905CT	±4%	TO-220	0 ~ +125°C	
Product Number	Output Voltage Tolerance	Package	Operating Temperature	
MC7905CT				
MC7906CT				
MC7908CT				
MC7909CT				
MC7910CT	±4%			
MC7912CT		TO-220	0 ~ +125°C	
MC7915CT		10-220	0~+125 0	
MC7918CT				
MC7924CT				
MC7905ACT				
MC7912ACT	±2%			
MC7915ACT				

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